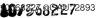
Receipt date: 02/14/2006



## IAP20 Ros'd FUTTO 14 FEB 2006

Customer No. 22,852 Attorney Docket No. **02814.0087** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:	)	
Viyian ALBERTS	)	
Application No.: Not Yet Assigned	)	Group Art Unit: Not Yet Assigned
Filed: February 14, 2006	)	Examiner: Not Yet Assigned
National Stage of International Application No. PCT/IB2004/051458 under 35 U.S.C. 371, for METHOD FOR THE PREPARATION OF GROUP IB-IIIA-VIA QUATERNARY OR HIGHER ALLOY SEMICONDUCTOR FILMS	) ) ) )	
MAIL STOP PCT		

MAIL STOP PCT Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

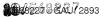
Sir

## INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)

Pursuant to 37 C.F.R. §§1.56 and 1.97(b), applicant brings to the Examiner's attention the documents listed on attached Form PTO/SB/08 and cited in the international search report. With exception of the U.S. patent, copies of the listed documents are attached. Applicant respectfully requests that the Examiner consider the documents listed on attached Form PTO/SB/08 and indicate that they were considered by making an appropriate notation on this form. This Information Disclosure Statement is being filed with the above-referenced application.

Also enclosed is an English-language international search report from the European Patent Office in the PCT international application, from which this national phase U.S. application is derived.

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that each or all of the listed documents are material or constitute "prior art." If the Examiner applies any of the Receipt date: 02/14/2006



Customer No. 22,852 Attorney Docket No. 02814.0087

documents as prior art against any claim in the application and applicant determines that the cited documents do not constitute "prior art" under United States law, applicant reserves the right to present to the Office the relevant facts and law regarding the appropriate status of such documents. Applicant further reserves the right to take appropriate action to establish the patentability of the disclosed invention over the listed documents, should one or more of the documents be applied against the claims of the present application.

If there is any fee due in connection with the filing of this Statement, please charge the fee to our Deposit Account No. 06-0916.

Respectfully submitted,

FINNEGAN, HENDERSON, FARABOW, GARRETT & DUNNER, L.L.P.

Ernest F. Chapmar Reg. No. 25,961

Dated: February 14, 2006

Enclosures EFC/FPD/sci

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Complete if Known IDS Form PTO/SB/08: Substitute for form 1449A/PTO Application Number Not Yet Assigned Filing Date February 14, 2006 / 5 (1) INFORMATION DISCLOSURE First Named Inventor STATEMENT BY APPLICANT Art Unit Not Yet Assigned (Use as many sheets as necessary) Examiner Name Not Yet Assigned Sheet Attorney Docket Number 02814.0087 1 of

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Examiner	ialo No 1		Issue or	Issue or Name of Patentee or Publication Date Applicant of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
Initials		Number-Kind Code <sup>2</sup> (# known)				
		US-5,436,204	07-25-1995	ALBIN et al.		
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Note: Copies of the U.S. Patent Documents are not Required in IDS filed after October 21, 2004

FOREIGN PATENT DOCUMENTS						
Examiner Initials	Cite No.1	Foreign Patent Document  Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>5</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Translation <sup>6</sup>

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Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Translation <sup>6</sup>		
		NAGOYA, Y. et al., "Role of Incorporated Sulfur Into the Surface of Cu(InGa)Se <sub>2</sub> Thin-Film Absorber," Solar Energy Materials & Solar Cells, Vol. 67, pp. 247-253, (2001).			
		KUSHIYA, K. et al., "Formation Chemistry of Polycrystalline Cul(nGa)Se, Thin-Film Absorbers Prepared by Selenization of Cu-Ga/In Stacked Precursor Layers with H <sub>2</sub> Se Gas," Mat. Res. Soc. Symp. Proc., Vol. 426, pp. 177-182, (1996).			
		KUSHIYA, K. et al., "Development of Cu(InGa)Se <sub>2</sub> Thin-Film Solar Cells With Zn-Compound Buffer," 13 <sup>th</sup> European Photovoltaic Solar Energy Conference, Nice, France, Vol. 2 of 2, Conf. 13, pp. 2016-2019, (October 1995).			
		KUSHIYA, K. et al., "The Role of Cu(lnGa)(SeS), Surface Layer on a Graded Band-Gap Cu(lnGa)Se <sub>2</sub> Thin- Film Solar Cell Prepared by Two-Stage Method," 25" IEEE Photovoltaic Specialists Conference, pp. 989- 992, (May 1996).			

Examiner	41 W D /	I Date	04/09/2009
Signature	/Matthew Reames/	Considered	04/03/2000
	/ Indication in tournous	Continuation	

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.